

# **Dual Channel 12-Bit 750 Msps Receiver and Feedback IC**

Check for Samples: ADS54T02

### **FEATURES**

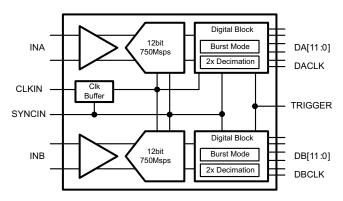
- Dual Channel
- 12-Bit Resolution
- Maximum Clock Rate: 750 Msps
- Low Swing Fullscale Input: 1.0 Vpp
- Analog Input Buffer with High Impedance Input
- Input Bandwidth (3dB): >1.2GHz
   Data Output Interface: DDR LVDS
- 196-Pin BGA Package (12x12mm)
- Power Dissipation: 1050mW/ch
   Performance at f<sub>in</sub> = 230 MHz IF
  - SNR: 60.7 dBFSSFDR: 78 dBc
- Performance at f<sub>in</sub> = 700 MHz IF
  - SNR: 58.9 dBFSSFDR: 73 dBc
- Receive Mode: 2x Decimation with Low Pass
  - or High Pass Filter
- Feedback Mode: Burst Mode Output for Full Bandwidth DPD Feedback

### **APPLICATIONS**

- Telecommunications Receiver
- Power Amplifier Linearization

#### DESCRIPTION

The ADS54T02 is a high linearity dual channel 12-bit, 750 MSPS analog-to-digital converter (ADC) easing front end filter design for wide bandwidth receivers. The analog input buffer isolates the internal switching of the on-chip track-and-hold from disturbing the signal source as well as providing a high-impedance input. Two output modes are available for the output data - it can be decimated by two or the data can be output in burst mode. The burst mode output is designed specifically for DPD feedback applications where high resolution output data is available for a short period of time. Designed for high SFDR, the ADC has low-noise performance and outstanding spurious-free dynamic range over a large inputfrequency range. The device is available in a 196pin BGA package and is specified over the full industrial temperature range (-40°C to 85°C).



Device Part No.	Number of Channels	Speed Grade
ADS54T02	2	750 Msps
ADS54T01	1	750 Msps
ADS54T04	2	500 Msps



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.





This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

### **DETAILED BLOCK DIAGRAM**

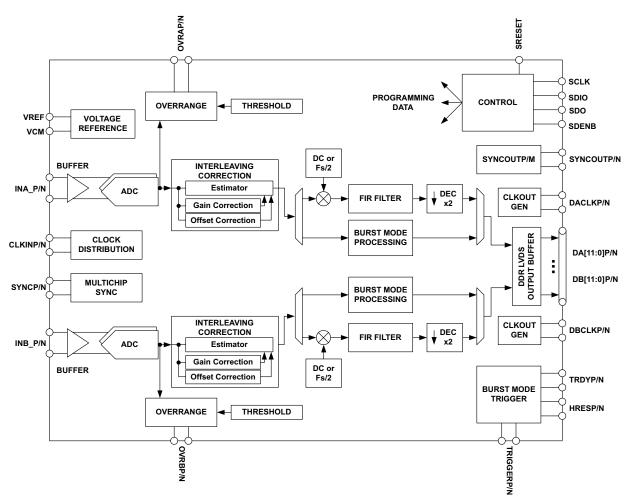


Figure 1. Detailed Block Diagram



### PINOUT INFORMATION

	Α	В	С	D	Е	F	G	Н	J	К	L	М	N	Р	
14	VREF	VCM	GND	INB_N	INB_P	GND	AVDDC	AVDDC	GND	INA_P	INA_N	GND	GND	CLKINP	14
13	SDENB	TEST MODE	GND	GND	GND	GND	GND	GND	GND	GND	GND	GND	GND	CLKINN	13
12	SCLK	SRESET	GND	AVDD33	AVDD33	AVDD33	AVDD33	AVDD33	AVDD33	AVDD33	AVDD33	GND	AVDD33	AVDD33	12
11	SDIO	ENABLE	GND	AVDD18	AVDD18	AVDD18	AVDD18	AVDD18	AVDD18	AVDD18	AVDD18	GND	AVDD18	AVDD18	11
10	SDO	IOVDD	GND	AVDD18	GND	GND	GND	GND	GND	GND	AVDD18	GND	TRIGGER N	TRIGGER P	10
9	DVDD	DVDD	GND	GND	GND	GND	GND	GND	GND	GND	GND	GND	SYNCN	SYNCP	9
8	DVDD	DVDD	DVDD	DVDD	GND	GND	GND	GND	GND	GND	DVDD	DVDD	DVDD	DVDD	8
7	DB0N	DB0P	DVDD LVDS	DVDD LVDS	GND	GND	GND	GND	GND	GND	DVDD LVDS	DVDD LVDS	TRDYN	TRDYP	7
6	DB1N	DB1P	DVDD LVDS	DVDD LVDS	GND	GND	GND	GND	GND	GND	DVDD LVDS	DVDD LVDS	HRESN	HRESP	6
5	DB2N	DB2P	OVRBN	OVRBP	GND	GND	GND	GND	GND	GND	OVRAN	OVRAP	SYNC OUTN	SYNC OUTP	5
4	DB3N	DB3P	DB8P	DB10P	NC	HRESP	TRDYP	DA0P	DA2P	DA4P	DA6P	DA8P	NC	NC	4
3	DB4N	DB4P	DB8N	DB10N	NC	HRESN	TRDYN	DA0N	DA2N	DA4N	DA6N	DA8N	DA11N	DA11P	3
2	DB5N	DB5P	DB7P	DB9P	DB11P	SYNC OUTP	DBCLKP	DACLKP	DA1P	DA3P	DA5P	DA7P	DA10N	DA10P	2
1	DB6N	DB6P	DB7N	DB9N	DB11N	SYNC OUTN	DBCLKN	DACLKN	DA1N	DA3N	DA5N	DA7N	DA9N	DA9P	1
	Α	В	С	D	E	F	G	Н	J	K	L	М	N	Р	

Figure 2. Pinout in DDR output mode (top down view)

### **PIN ASSIGNMENTS**

		1	
	PIN	1/0	DESCRIPTION
NAME NUMBER		1/0	DESCRIPTION
INPUT/REFER	ENCE		
INA_P/N	K14, L14	I	Analog ADC A differential input signal.
INB_P/N	E14, D14	I	Analog ADC B differential input signal.
VCM	B14	0	Output of the analog input common mode (nominally 1.9V). A 0.1µF capacitor to AGND is recommended.
VREF	A14	0	Reference voltage output. A 0.1µF capacitor to AGND is recommended, but not required.
CLOCK/SYNC			
CLKINP/N	P14, P13	I	Differential input clock
SYNCP/N	P9, N9	ı	Synchronization input. Inactive if logic low. When clocked in a high state initially, this is used for resetting internal clocks and digital logic and starting the SYNCOUT signal. Internal $100\Omega$ termination.
CONTROL/SE	RIAL	•	
SRESET	B12	I	Serial interface reset input. Active low. Initialized internal registers during high to low transition. Asynchronous. Internal $50k\Omega$ pull up resistor to IOVDD.



## **PIN ASSIGNMENTS (continued)**

PIN							
NAME	NUMBER	1/0	DESCRIPTION				
ENABLE	B11	ı	Chip enable – active high. Power down function can be controlled through SPI register assignment. Internal $50k\Omega$ pull up resistor to IOVDD.				
SCLK	A12	I	Serial interface clock. Internal 50kΩ pull-down resistor.				
SDIO	A11	I/O	Bi-directional serial data in 3 pin mode (default). In 4-pin interface mode (register x00, D16), the SDIO pin in an input only. Internal $50k\Omega$ pull-down.				
SDENB	A13	I	Serial interface enable. Internal 50kΩ pull-down resistor.				
SDO	A10	0	Uni-directional serial interface data in 4 pin mode (register x00, D16). The SDO pin is tristated in 3-pin interface mode (default). Internal $50k\Omega$ pull-down resistor.				
TESTMODE	B13	_	Factory internal test, do not connect				
DATA INTERFAC	CE						
DA[11:0]P/N	P3, N3, P2, N2, P1, N1, M4, M3, M2, M1, L4, L3, L2, L1, K4, K3, K2, K1, J4, J3, J2, J1, H4, H3	0	ADC A Data Bits 11 (MSB) to 0 (LSB) in DDR output mode. Standard LVDS output.				
DB[11:0]P/N	E2, E1, D4, D3, D2, D1, C4, C3, C2, C1, B1, A1, B2, A2, B3, A3, B4, A4, B5, A5, B6, A6, B7, A7	0	ADC B Data Bits 11 (MSB) to 0 (LSB) in DDR output mode. Standard LVDS output.				
DACLKP/N	H2, H1	0	DDR differential output data clock for Bus A. Register programmable to provide either rising or falling edge to center of stable data nominal timing.				
DBCLKP/N	G2, G1	0	DDR differential output data clock for Bus B. Register programmable to provide either rising or falling edge to center of stable data nominal timing. Optionally Bus B can be latched with DACLKP/N.				
SYNCOUTP/N	F2, F1, P5, N5	0	Synchronization output signal for synchronizing multiple ADCs. Can be disabled via SPI.				
OVRAP/N	M5, L5	0	Bus A, Overrange indicator, LVDS output. A logic high signals an analog input in excess of the full-scale range. Optional SYNC output.				
OVRBP/N	D5, C5	0	Bus B, Overrange indicator, LVDS output. A logic high signals an analog input in excess of the full-scale range. Optional SYNC output.				
TRIGGERP/N	P10, N10	I	Trigger used for High resolution output data in feedback mode. Internal $100\Omega$ termination				
TRDYP/N	G4, G3, P7, N7	0	Trigger ready output indicator. Outputs for chA and chB are identical and one output can be shared for both channels.				
HRESP/N	F4, F3, P6, N6	0	Indicator for high resolution output data—logic high signals 12bit output data. Outputs for chA and chB are identical and one output can be shared for both channels.				
NC	E3, E4, N4, P4	-	Don't connect to pin				
POWER SUPPLY	<i>(</i>						
AVDD33	D12, E12, F12, G12, H12, J12, K12, L12, N12, P12	I	3.3V analog supply				
AVDDC	G14, H14	I	1.8V supply for clock input				
AVDD18	D10, D11, E11, F11, G11, H11, J11, K11, L10, L11, N11, P11	I	1.8V analog supply				
DVDD	A8, A9, B8, B9, C8, D8, L8, M8, N8, P8	I	1.8V supply for digital block				
DVDDLVDS	C6, C7, D6, D7, L6, L7, M6, M7	I	1.8V supply for LVDS outputs				
IOVDD	B10	I	1.8V for digital I/Os				
GND		I	Ground				

Product Folder Links: ADS54T02



#### **PACKAGE/ORDERING INFORMATION**

PRODUCT	PACKAGE- LEAD	PACKAGE DESIGNATOR	SPECIFIED TEMPERATURE RANGE	ECO PLAN <sup>(2)</sup>	LEAD/ BALL FINISH	PACKAGE MARKING	ORDERING NUMBER	TRANSPORT MEDIA, QUANTITY
				GREEN			ADS54T02IZAY	Tray
ADS54T02	196-BGA	ZAY	–40°C to 85°C	(RoHS & no Sb/Br)		ADS54T02I	ADS54T02IZAYR	Tape and Reel

#### **ABSOLUTE MAXIMUM RATINGS**

over operating free-air temperature range (unless otherwise noted)

		V	ALUE	UNIT	
		MIN	MIN MAX		
Supply voltage range, AVDD3	3	-0.5	4	V	
Supply voltage range, AVDDO	;	-0.5	2.3	V	
Supply voltage range, AVDD1	8	-0.5	2.3	V	
Supply voltage range, DVDD	-0.5	2.3	V		
Supply voltage range, DVDDL	-0.5	2.3	V		
Supply voltage range, IOVDD		-0.5	4	V	
	INA/B_P, INA/B_N	-0.5	AVDD33 + 0.5	V	
Valtana annii ad ta innut nina	CLKINP, CLKINN	-0.5	AVDDC + 0.5	V	
Voltage applied to input pins	SYNCP, SYNCN	-0.5	AVDD33 + 0.5	V	
	SRESET, SDENB, SCLK, SDIO, SDO, ENABLE	-0.5	IOVDD + 0.5	V	
Operating free-air temperature	e range, T <sub>A</sub>	-40	85	°C	
Operating junction temperatur		150	°C		
Storage temperature range		-65	150	°C	
ESD, Human Body Model		2	kV		

### THERMAL INFORMATION

		ADS54T02	
	THERMAL METRIC <sup>(1)</sup>	nFBGA	UNITS
		196 PINS	
$\theta_{JA}$	Junction-to-ambient thermal resistance (2)	37.6	
9 <sub>JCtop</sub>	Junction-to-case (top) thermal resistance (3)	6.8	
θ <sub>JB</sub>	Junction-to-board thermal resistance (4)	16.8	0000
Ψлт	Junction-to-top characterization parameter <sup>(5)</sup>	0.2	°C/W
Ψјв	Junction-to-board characterization parameter (6)	16.4	
$\theta_{JCbot}$	Junction-to-case (bottom) thermal resistance (7)	N/A	

- (1) For more information about traditional and new thermal metrics, see the IC Package Thermal Metrics application report, SPRA953.
- (2) The junction-to-ambient thermal resistance under natural convection is obtained in a simulation on a JEDEC-standard, high-K board, as specified in JESD51-7, in an environment described in JESD51-2a.
- (3) The junction-to-case (top) thermal resistance is obtained by simulating a cold plate test on the package top. No specific JEDEC-standard test exists, but a close description can be found in the ANSI SEMI standard G30-88.
- (4) The junction-to-board thermal resistance is obtained by simulating in an environment with a ring cold plate fixture to control the PCB temperature, as described in JESD51-8.
- (5) The junction-to-top characterization parameter, ψ<sub>JT</sub>, estimates the junction temperature of a device in a real system and is extracted from the simulation data for obtaining θ<sub>JA</sub>, using a procedure described in JESD51-2a (sections 6 and 7).
- (6) The junction-to-board characterization parameter, ψ<sub>JB</sub>, estimates the junction temperature of a device in a real system and is extracted from the simulation data for obtaining θ<sub>JA</sub>, using a procedure described in JESD51-2a (sections 6 and 7).
- (7) The junction-to-case (bottom) thermal resistance is obtained by simulating a cold plate test on the exposed (power) pad. No specific JEDEC standard test exists, but a close description can be found in the ANSI SEMI standard G30-88.



### RECOMMENDED OPERATING CONDITIONS

over operating free-air temperature range (unless otherwise noted)

		MIN	NOM	MAX	UNIT
_	Recommended operating junction temperature			105	۰.
IJ	Maximum rated operating junction temperature <sup>(1)</sup>	125			٠.
$T_A$	Recommended free-air temperature	-40	25	85	°C

<sup>(1)</sup> Prolonged use at this junction temperature may increase the device failure-in-time (FIT) rate.

### **ELECTRICAL CHARACTERISTICS**

Typical values at  $T_A = 25^{\circ}\text{C}$ , full temperature range is  $T_{MIN} = -40^{\circ}\text{C}$  to  $T_{MAX} = 85^{\circ}\text{C}$ , ADC sampling rate = 750Msps, 50% clock duty cycle, AVDD33 = 3.3V, AVDDC/AVDD18/DVDD/DVDDLVDS/IOVDD = 1.8V, -1dBFS differential input (unless otherwise noted).

PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNITS
ADC Clock Frequency				750	MSPS
Resolution		12			Bits
SUPPLY					
AVDD33		3.15	3.3	3.45	V
AVDDC, AVDD18, DVDD, DVDDLVDS		1.7	1.8	1.9	V
IOVDD		1.7	1.8	3.45	V
POWER SUPPLY					
I <sub>AVDD33</sub> 3.3V Analog supply current			303	350	mA
I <sub>AVDD18</sub> 1.8V Analog supply current			103	120	mA
I <sub>AVDDC</sub> 1.8V Clock supply current			41	60	mA
I <sub>DVDD</sub> 1.8V Digital supply current	Auto Correction Enabled		323	400	mA
I <sub>DVDD</sub> 1.8V Digital supply current	Auto Correction Disabled		155		mA
I <sub>DVDD</sub> 1.8V Digital supply current	Auto Correction Disabled, decimation filter enabled		184		mA
I <sub>DVDDLVDS</sub> 1.8V LVDS supply current			125	150	mA
I <sub>IOVDD</sub> 1.8V I/O Voltage supply current			1	2	mA
P <sub>dis</sub> Total power dissipation	Auto Correction Enabled, decimation filter disabled		2.1	2.5	W
P <sub>dis</sub> Total power dissipation	Auto Correction Disabled, decimation filter disabled		1.76		W
PSRR	250kHz to 500MHz	40			dB
Shut-down power dissipation			7		mW
Shut-down wake up time			2.5		ms
Standby power dissipation			7		mW
Standby wake up time			100		μs
Deep-sleep mode power dissipation	Auto correction disabled		282		mW
peeh-sieeh mode hower dissibation	Auto correction enabled		358		mW
Deep-sleep mode wakeup time			20		μs
Light closs made never dissinction	Auto correction disabled		549		mW
Light-sleep mode power dissipation	Auto correction enabled		665		mW
Light-sleep mode wakeup time			2		μs



## **ELECTRICAL CHARACTERISTICS**

Typical values at  $T_A = 25^{\circ}\text{C}$ , full temperature range is  $T_{MIN} = -40^{\circ}\text{C}$  to  $T_{MAX} = 85^{\circ}\text{C}$ , ADC sampling rate = 750Msps, 50% clock duty cycle, AVDD3V = 3.3V, AVDD/DRVDD/IOVDD = 1.8V, -1dBFS differential input (unless otherwise noted).

PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNITS
ANALOG INPUTS		1			
Differential input full-scale			1.0	1.25	Vpp
Input common mode voltage			1.9	±0.1	٧
Input resistance	Differential at DC		1		kΩ
Input capacitance	Each input to GND		2		pF
VCM common mode voltage output			1.9		٧
Analog input bandwidth (3dB)			1200		MHz
DYNAMIC ACCURACY					
Offset Error	Auto Correction Disabled	-20	-7.5	20	mV
Oliset Elloi	Auto Correction Enabled	-1	0	1	mV
Offset temperature coefficient			-611		μV/°C
Gain error		-5		5	%FS
Gain temperature coefficient			0.005		%FS/°C
Differential nonlinearity	f <sub>IN</sub> = 230 MHz	-1	±0.9	2	LSB
Integral nonlinearity	f <sub>IN</sub> = 230 MHz	-5	±1.5	5	LSB
CLOCK INPUT	·				
Input clock frequency				750	MHz
Input clock amplitude			2		Vpp
Input clock duty cycle		40%	50%	60%	
Internal clock biasing			0.9		V



### **ELECTRICAL CHARACTERISTICS**

Typical values at  $T_A = 25^{\circ}\text{C}$ , full temperature range is  $T_{\text{MIN}} = -40^{\circ}\text{C}$  to  $T_{\text{MAX}} = 85^{\circ}\text{C}$ , ADC sampling rate = 750Msps, 50% clock duty cycle, AVDD33 = 3.3V, AVDDC/AVDD18/DVDD/DVDDLVDS/IOVDD = 1.8V, -1dBFS differential input (unless otherwise noted).

	PARAMETER	TEST CONDITIONS	MIN	TYP MAX	MIN TYP MAX	UNITS
Auto Co	rrection			Enabled	Disabled	Vpp
DYNAMI	C AC CHARACTERISTICS <sup>(1)</sup> –	Burst Mode Enabled: 12bit High	Resolution	Output Data		
		f <sub>IN</sub> = 10 MHz		61.1	61.2	
		f <sub>IN</sub> = 100 MHz		61	61.1	
SNR	Signal to Noise Ratio	f <sub>IN</sub> = 230 MHz	59	60.7	60.9	dBFS
		f <sub>IN</sub> = 450 MHz		60	60.7	
		f <sub>IN</sub> = 700 MHz		58.9	60	
		f <sub>IN</sub> = 10 MHz		81	85	
		f <sub>IN</sub> = 100 MHz		76	81	
HD2,3	Second and third harmonic distortion	f <sub>IN</sub> = 230 MHz	68	78	78	dBc
	distortion	f <sub>IN</sub> = 450 MHz		79	78	
		f <sub>IN</sub> = 700 MHz		76	78	
		f <sub>IN</sub> = 10 MHz		81	83	
	Spur Free Dynamic Range	f <sub>IN</sub> = 100 MHz		81	82	
Non HD2,3	(excluding second and third harmonic distortion and Fs/2 – F <sub>IN</sub> spur)	f <sub>IN</sub> = 230 MHz	68	79	81	dBc
1102,5		f <sub>IN</sub> = 450 MHz		77	81	
		f <sub>IN</sub> = 700 MHz		73	82	
	Fs/2-Fin interleaving spur	f <sub>IN</sub> = 10 MHz		90	86	
		f <sub>IN</sub> = 100 MHz		83	83	
IL		f <sub>IN</sub> = 230 MHz	65	78	77	dBc
		f <sub>IN</sub> = 450 MHz		75	74	
		f <sub>IN</sub> = 700 MHz		73	69	
		f <sub>IN</sub> = 10 MHz		61	61.1	
		f <sub>IN</sub> = 100 MHz		60.8	61	
SINAD	Signal to noise and distortion ratio	f <sub>IN</sub> = 230 MHz	57.5	60.5	60.8	dBc
	iano	f <sub>IN</sub> = 450 MHz		59.8	60.3	
		f <sub>IN</sub> = 700 MHz		58.4	59.4	
		f <sub>IN</sub> = 10 MHz		76	76.5	
		f <sub>IN</sub> = 100 MHz		73	76	
THD	Total Harmonic Distortion	f <sub>IN</sub> = 230 MHz	66	74	74	dBc
		f <sub>IN</sub> = 450 MHz		74	73	
		f <sub>IN</sub> = 700 MHz		72	74	
IMD3	Inter modulation distortion	F <sub>in</sub> = 129.5 and 130.5MHz, - 7dBFS		82	83	dDEC
IMD3	Inter modulation distortion	F <sub>in</sub> = 349.5 and 350.5MHz, - 7dBFS		76	77	dBFS
	Crosstalk			90	90	dB
ENOB	Effective number of bits	f <sub>IN</sub> = 230 MHz		9.8	9.8	LSB

<sup>(1)</sup> SFDR and SNR calculations do not include the DC or Fs/2 bins when Auto Correction is disabled.

Submit Documentation Feedback

Copyright © 2013–2014, Texas Instruments Incorporated



### **ELECTRICAL CHARACTERISTICS**

Typical values at  $T_A = 25^{\circ}\text{C}$ , full temperature range is  $T_{\text{MIN}} = -40^{\circ}\text{C}$  to  $T_{\text{MAX}} = 85^{\circ}\text{C}$ , ADC sampling rate = 750Msps, 50% clock duty cycle, AVDD33 = 3.3V, AVDDC/AVDD18/DVDD/DVDDLVDS/IOVDD = 1.8V, -1dBFS differential input (unless otherwise noted).

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNITS
OVER	-DRIVE RECOVERY ERROF	8				
	Input overload recovery	Recovery to within 5% (of final value) for 6dB overload with sine wave input		2		ns
SAMP	LE TIMING CHARACTERIS	TICS				
rms	Aperture Jitter	Sample uncertainty		100		fs rms
		ADC sample to digital output, auto correction disabled		38		Clock
		ADC sample to digital output, auto correction enabled		50		Cycles
	Data Latency	ADC sample to digital output, Decimation filter enabled, Auto correction disabled		74		Sampling clock Cycles
	Over-range Latency	ADC sample to over-range output		12		Clock Cycles

### **ELECTRICAL CHARACTERISTICS**

The DC specifications refer to the condition where the digital outputs are not switching, but are permanently at a valid logic level 0 or 1. AVDD33 = 3.3V, AVDDC/AVDD18/DVDD/DVDDLVDS/IOVDD = 1.8V

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNITS
DIGITA	L INPUTS – SRESET, SCLK, SDE	NB, SDIO, ENABLE			<u>.</u>	
	High-level input voltage	All digital inputs support 1.8V and 3.3V logic	0.7 x IOVDD			V
	Low-level input voltage	levels.			0.3 x IOVDD	V
	High-level input current		-50		200	μΑ
	Low-level input current		-50		50	μΑ
	Input capacitance			5		pF
DIGITA	L OUTPUTS – SDO					
	High-level output voltage	Iload = -100uA	IOVDD – 0.2			V
	r light-level output voltage	Iload = -2mA	0.8 x IOVDD			V
		Iload = 100uA			0.2	
	Low-level output voltage	Iload = 2mA			0.22 x IOVDD	V
DIGITA	L INPUTS – SYNCP/N, TRIGGERF	P/N				
$V_{\text{ID}}$	Differential input voltage		250	350	450	mV
$V_{\text{CM}}$	Input common mode voltage		1.125	1.2	1.375	V
$t_{SU}$			500			ps
DIGITA	L OUTPUTS – DA[11:0]P/N, DACL	LKP/N, OVRAP/N, SYNCOUTP/N, TRDYP/N, HF	RESP/N, DB[11:0	)]P/N, DBC	LKP/N, O\	/RBP/N,
$V_{OD}$	Output differential voltage	lout = 3.5mA	250	350	450	mV
$V_{OCM}$	Output common mode voltage	lout = 3.5mA	1.125	1.25	1.375	V
$t_{suA}$		$F_s$ = 750Msps, Data valid to zero-crossing of DACLK	320	400		ps
t <sub>hA</sub>		F <sub>s</sub> = 750Msps, Zero-crossing of DACLK to data becoming invalid	250	320		ps
t <sub>suB</sub>		$F_s = 750 Msps$ , Data valid to zero-crossing of DBCLK	400	460		ps
t <sub>hB</sub>		F <sub>s</sub> = 750Msps, Zero-crossing of DBCLK to data becoming invalid	300	370		ps



The DC specifications refer to the condition where the digital outputs are not switching, but are permanently at a valid logic level 0 or 1. AVDD33 = 3.3V, AVDDC/AVDD18/DVDD/DVDDLVDS/IOVDD = 1.8V

PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNITS
t <sub>PD</sub>	F <sub>s</sub> = 750Msps, CLKIN falling edge to DACLK, DBCLK rising edge	3.36	3.69	3.92	ns
t <sub>RISE</sub>	10% - 90%	100	150	200	ps
t <sub>FALL</sub>	90% - 10%	100	150	200	ps

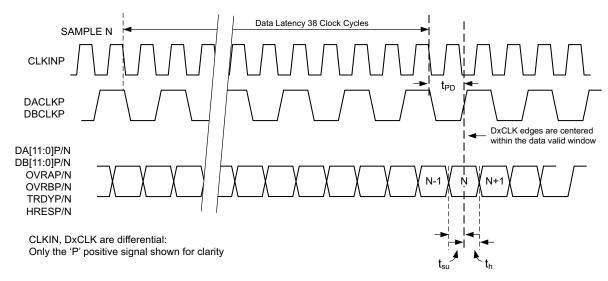
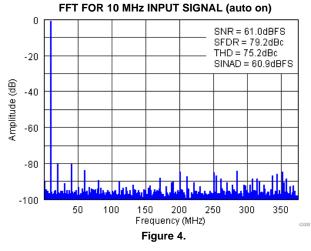


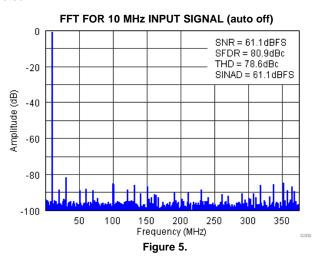
Figure 3. Timing Diagram for 12-bit DDR Output

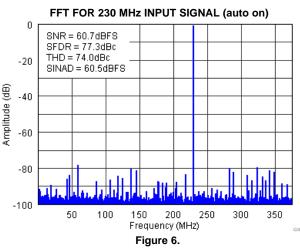


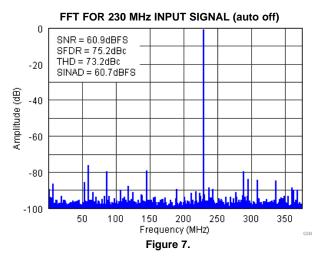
#### TYPICAL CHARACTERISTICS

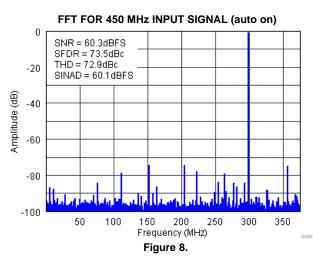
Typical values at TA =  $+25^{\circ}$ C, full temperature range is T<sub>MIN</sub> =  $-40^{\circ}$ C to T<sub>MAX</sub> =  $+85^{\circ}$ C, ADC sampling rate = 750Msps, 50% clock duty cycle, AVDD33 = 3.3V, AVDDC/AVDD18/DVDD/DVDDLVDS/IOVDD = 1.8V, -1dBFS differential input, unless otherwise noted.

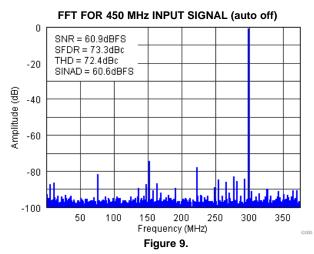








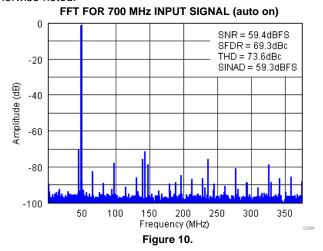


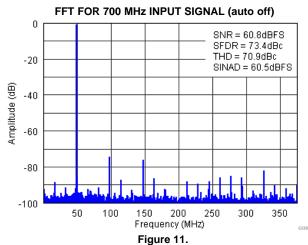


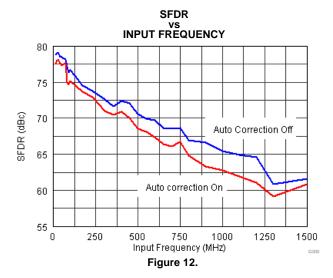
Copyright © 2013–2014, Texas Instruments Incorporated

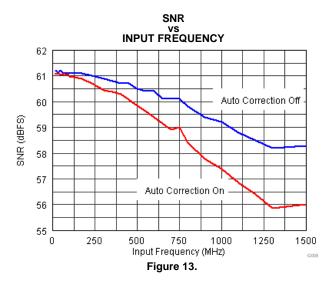


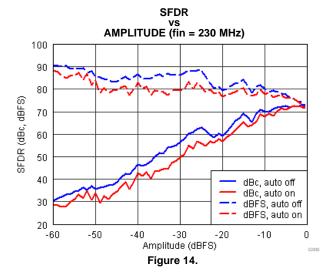
Typical values at TA =  $\pm 25^{\circ}$ C, full temperature range is  $T_{MIN} = -40^{\circ}$ C to  $T_{MAX} = \pm 85^{\circ}$ C, ADC sampling rate = 750Msps, 50% clock duty cycle, AVDD33 = 3.3V, AVDDC/AVDD18/DVDD/DVDDLVDS/IOVDD = 1.8V,  $\pm 1.8$ V,  $\pm 1.8$ V,

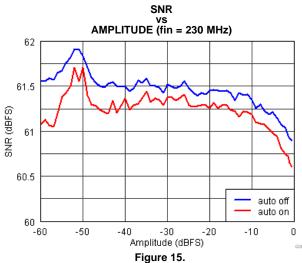






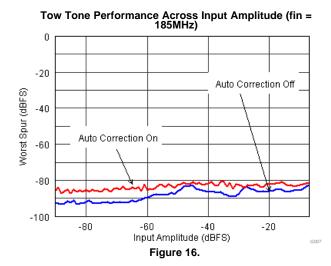


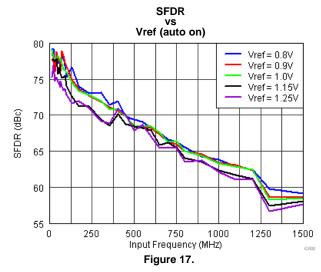


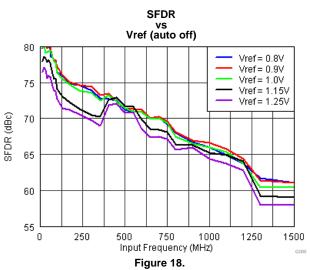


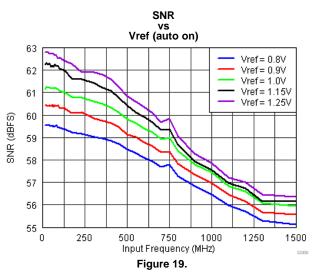


Typical values at TA =  $+25^{\circ}$ C, full temperature range is  $T_{MIN} = -40^{\circ}$ C to  $T_{MAX} = +85^{\circ}$ C, ADC sampling rate = 750Msps, 50% clock duty cycle, AVDD33 = 3.3V, AVDDC/AVDD18/DVDD/DVDDLVDS/IOVDD = 1.8V, -1dBFS differential input, unless otherwise noted.





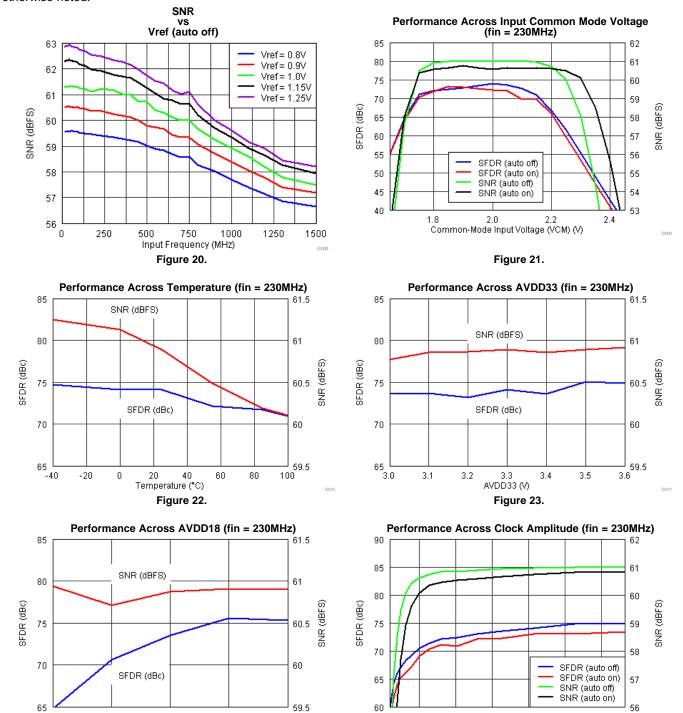




Copyright © 2013–2014, Texas Instruments Incorporated



Typical values at TA = +25°C, full temperature range is  $T_{MIN}$  = -40°C to  $T_{MAX}$  = +85°C, ADC sampling rate = 750Msps, 50% clock duty cycle, AVDD33 = 3.3V, AVDDC/AVDD18/DVDD/DVDDLVDS/IOVDD = 1.8V, -1dBFS differential input, unless otherwise noted.



1.7

1.8

AVDD18 (V)

Figure 24.

1.9

2.0

2.5

3.0

1.6

0.5

1.0

1.5

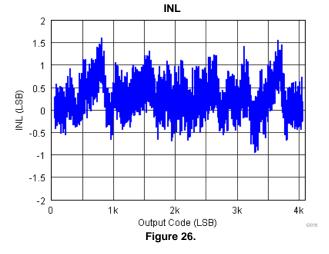
Differential Clock Amplitude (Vpp)

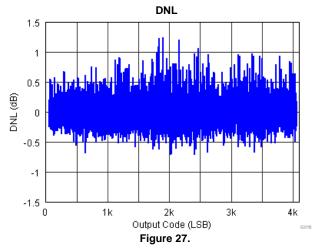
Figure 25.

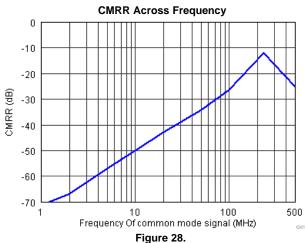
2.0

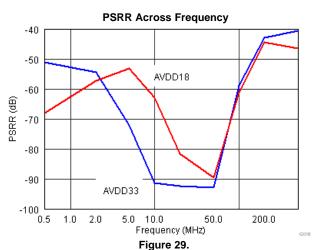


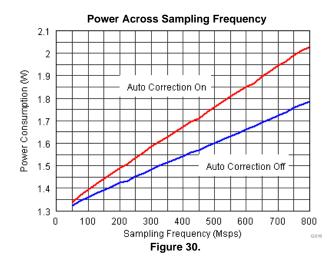
Typical values at TA =  $+25^{\circ}$ C, full temperature range is  $T_{MIN} = -40^{\circ}$ C to  $T_{MAX} = +85^{\circ}$ C, ADC sampling rate = 750Msps, 50% clock duty cycle, AVDD33 = 3.3V, AVDDC/AVDD18/DVDD/DVDDLVDS/IOVDD = 1.8V, -1dBFS differential input, unless otherwise noted.













Typical values at TA =  $+25^{\circ}$ C, full temperature range is  $T_{MIN} = -40^{\circ}$ C to  $T_{MAX} = +85^{\circ}$ C, ADC sampling rate = 750Msps, 50% clock duty cycle, AVDD33 = 3.3V, AVDDC/AVDD18/DVDD/DVDDLVDS/IOVDD = 1.8V, -1dBFS differential input, unless otherwise noted.

### SFDR Across Input and Sampling Frequencies (auto on)

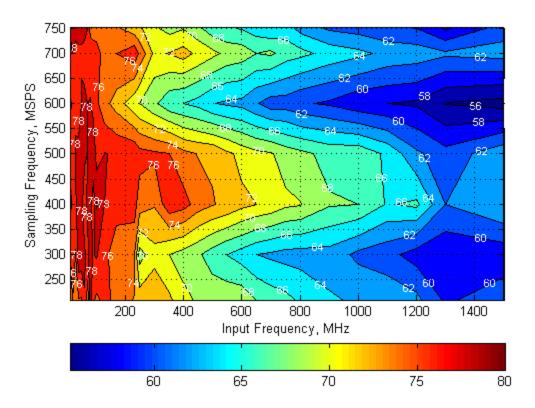


Figure 31.



Typical values at TA = +25°C, full temperature range is  $T_{MIN}$  = -40°C to  $T_{MAX}$  = +85°C, ADC sampling rate = 750Msps, 50% clock duty cycle, AVDD33 = 3.3V, AVDDC/AVDD18/DVDD/DVDDLVDS/IOVDD = 1.8V, -1dBFS differential input, unless otherwise noted.

### SFDR Across Input and Sampling Frequencies (auto off)

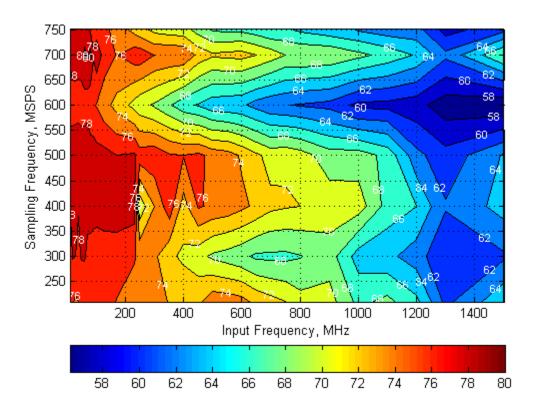


Figure 32.



Typical values at TA = +25°C, full temperature range is  $T_{MIN}$  = -40°C to  $T_{MAX}$  = +85°C, ADC sampling rate = 750Msps, 50% clock duty cycle, AVDD33 = 3.3V, AVDDC/AVDD18/DVDD/DVDDLVDS/IOVDD = 1.8V, -1dBFS differential input, unless otherwise noted.

#### SNR Across Input and Sampling Frequencies (auto on)

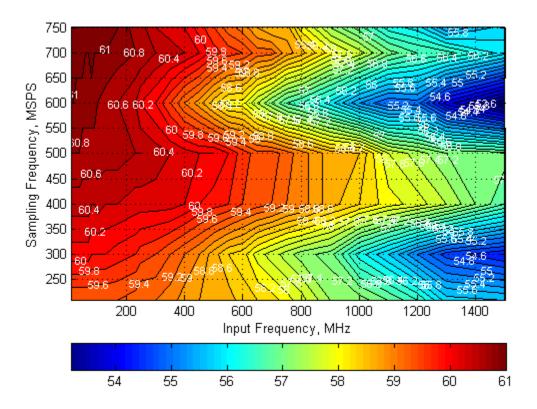


Figure 33.



Typical values at TA = +25°C, full temperature range is  $T_{MIN}$  = -40°C to  $T_{MAX}$  = +85°C, ADC sampling rate = 750Msps, 50% clock duty cycle, AVDD33 = 3.3V, AVDDC/AVDD18/DVDD/DVDDLVDS/IOVDD = 1.8V, -1dBFS differential input, unless otherwise noted.

### SNR Across Input and Sampling Frequencies (auto on)

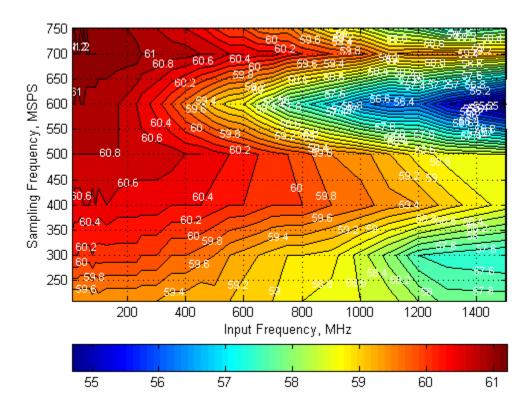


Figure 34.

Copyright © 2013–2014, Texas Instruments Incorporated



#### **FEATURES**

#### **POWER DOWN MODES**

The ADS54T02 can be configured via SPI write (address x37) to a stand-by, light or deep sleep power mode which is controlled by the ENABLE pin. The sleep modes are active when the ENABLE pin goes low. Different internal functions stay powered up which results in different power consumption and wake up time between the two sleep modes.

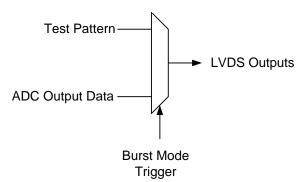
Sleep mode	Wake up time	Power Consumption Auto correction disabled	Power Consumption Auto correction enabled
Complete Shut Down	2.5 ms	7 mW	7 mW
Stand-by	100 µs	7 mW	7 mW
Deep Sleep	20 μs	292 mW	358 mW
Light Sleep	2 µs	549 mW	655 mW

### **TEST PATTERN OUTPUT**

The ADS54T02 can be configured to output different test patterns that can be used to verify the digital interface is connected and working properly. To enable the test pattern mode, the high performance mode 1 has to be disabled first via SPI register write. Then different test patterns can be selected by configuring registers x3C, x3D and x3E. All three registers must be configured for the test pattern to work properly.

First set HP1 = 0 (Addr 0x01, D01)

Internally the test pattern replaces the sampled data from the ADC. However at the LVDS outputs the output data is still subject to burst mode operation. In low resolution output the LSBs of the test pattern are replaced with 0s.



Register Address	All 0s	All 1s	Toggle (0xAAA => 0x555)	Toggle (0xFFF => 0x000)
0x3C	0x8000	0xBFFC	0x9554	0xBFFC
0x3D	0x0000	0x3FFC	0x2AA8	0x0000
0x3E	0x0000	0x3FFC	0x1554	0x3FFC

Register Address		Custom Pattern														
	D15	D14	D13	D12	D11	D10	D9	D8	D7	D6	D5	D4	D3	D2	D1	D0
x3C	1	0													0	0
x3D	0	0	D11	D10	D9	D8	D7	D6	D5	D4	D3	D2	D1	D0	0	0
x3E	0	0													0	0

For normal operation, set HP1 = 1 (Addr 0x01, D01) and 0x3C, 0x3D, 0x3E all to 0.



#### **CLOCK INPUT**

The ADS54T02 clock input can be driven differentially with a sine wave, LVPECL or LVDS source with little or no difference in performance. The common mode voltage of the clock input is set to 0.9V using internal  $2k\Omega$  resistors. This allows for AC coupling of the clock inputs. The termination resistors should be placed as close as possible to the clock inputs in order to minimize signal reflections and jitter degradation.

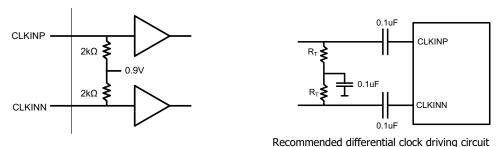


Figure 35. Recommended Differential Clock Driving Circuit

#### **SNR AND CLOCK JITTER**

The signal to noise ratio of the ADC is limited by three different factors: the quantization noise is typically not noticeable in pipeline converters and is 72dB for a 12bit ADC. The thermal noise limits the SNR at low input frequencies while the clock jitter sets the SNR for higher input frequencies.

$$SNR_{ADC}[dBc] = -20 \times log \sqrt{10 - \frac{SNR_{Quantization\_Noise}}{20}}^2 + \left(10 - \frac{SNR_{ThermalNoise}}{20}\right)^2 + \left(10 - \frac{SNR_{Jitter}}{20}\right)^2}$$
(1)

The SNR limitation due to sample clock jitter can be calculated as following:

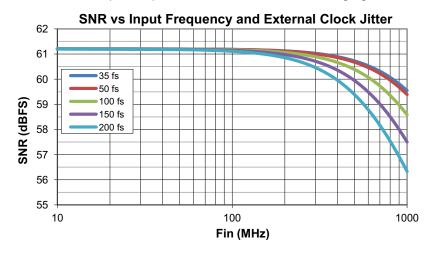
$$SNR_{Jitter} [dBc] = -20 \times log(2\pi \times f_{IN} \times t_{Jitter})$$
(2)

The total clock jitter (TJitter) has three components – the internal aperture jitter (100fs for ADS54T02) which is set by the noise of the clock input buffer, the external clock jitter and the jitter from the analog input signal. It can be calculated as following:

$$T_{\text{Jitter}} = \sqrt{\left(T_{\text{Jitter,Ext.Clock\_Input}}\right)^2 + \left(T_{\text{Aperture\_ADC}}\right)^2}$$
(3)

External clock jitter can be minimized by using high quality clock sources and jitter cleaners as well as bandpass filters at the clock input while a faster clock slew rate improves the ADC aperture jitter.

The ADS54T02 has a thermal noise of 61.2 dBFS and internal aperture jitter of 100fs. The SNR depending on amount of external jitter for different input frequencies is shown in the following figure.

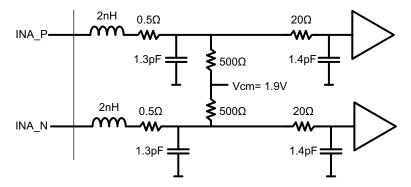




#### **ANALOG INPUTS**

The ADS54T02 analog signal inputs are designed to be driven differentially. The analog input pins have internal analog buffers that drive the sampling circuit. As a result of the analog buffer, the input pins present a high impedance input across a very wide frequency range to the external driving source which enables great flexibility in the external analog filter design as well as excellent  $50\Omega$  matching for RF applications. The buffer also helps to isolate the external driving circuit from the internal switching currents of the sampling circuit which results in a more constant SFDR performance across input frequencies.

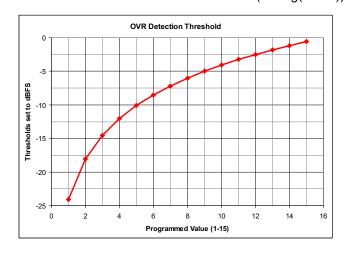
The common-mode voltage of the signal inputs is internally biased to 1.9V using  $500\Omega$  resistors which allows for AC coupling of the input drive network. Each input pin (INP, INM) must swing symmetrically between (VCM + 0.25V) and (VCM - 0.25V), resulting in a 1.0Vpp (default) differential input swing. The input sampling circuit has a 3dB bandwidth that extends up to 1.2GHz.



#### **OVER-RANGE INDICATION**

The ADS54T02 provides a fast over-range indication on the OVRA/B pins. The fast OVR is triggered if the input voltage exceeds the programmable overrange threshold and it gets presented after just 12 clock cycles enabling a quicker reaction to an overrange event. The OVR threshold can be configured using SPI register writes.

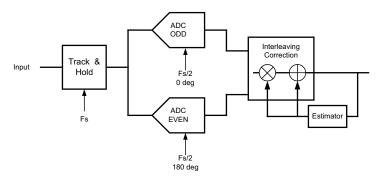
The input voltage level at which the overload is detected is referred to as the threshold and is programmable using the Over-range threshold bits. The threshold at which fast OVR is triggered is (full-scale × [the decimal value of the FAST OVR THRESH bits] /16). After reset, the default value of the over-range threshold is set to 15 (decimal) which corresponds to a threshold of 0.56dB below full scale (20\*log(15/16)).





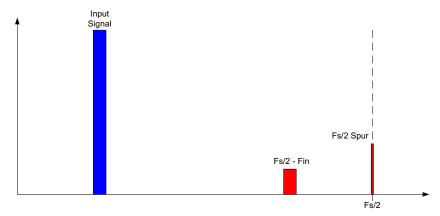
#### INTERLEAVING CORRECTION

Each of the two data converter channels consists of two interleaved ADCs each operating at half of the ADC sampling rate but 180° out of phase from each other. The front end track and hold circuitry is operating at the full ADC sampling rate which minimizes the timing mismatch between the two interleaved ADCs. In addition the ADS54T02 is equipped with internal interleaving correction logic that can be enabled via SPI register write.



The interleaving operation creates 2 distinct and interleaving products:

- Fs/2 Fin: this spur is created by gain timing mismatch between the ADCs. Since internally the front end track and hold is operated at the full sampling rate, this component is greatly improved and mostly dependent on gain mismatch.
- · Fs/2 Spur: due to offset mismatch between ADCs



The auto correction loop can be enabled via SPI register write in address 0x01. By default it is disabled for lowest possible power consumption. The default settings for the auto correction function should work for most applications. However please contact Texas Instruments if further fine tuning of the algorithm is required.

The auto correction function yields best performance for input frequencies below 250MHz.



#### RECEIVE MODE: DECIMATION FILTER

Each channel has a digital filter in the data path as shown in Figure 36. The filter can be programmed as a lowpass or a high-pass filter and the normalized frequency response of both filters is shown in Figure 37.

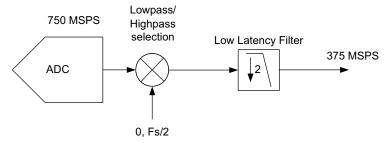


Figure 36.

The decimation filter response has a 0.1dB pass band ripple with approximately 41% pass-band bandwidth. The stop-band attenuation is approximately 40dB.

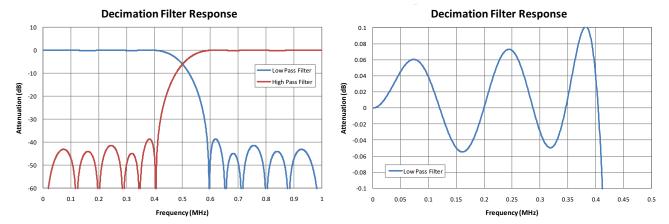


Figure 37.

Product Folder Links: ADS54T02

24



#### FEEDBACK MODE: BURST MODE

In burst mode the output data is alternated between a high resolution 12bit output of  $2^N$  samples and a low resolution 7 or 11bit output of  $2^{N+3}$  samples. Burst mode is enabled through SPI register write and there are two basic operating modes available – a manual trigger mode where the high resolution output is initiated through external trigger and an auto trigger mode where the internal logic transitions to high resolution output immediately after transmitting the last low resolution sample. Upon enabling burst mode through a SPI register write, the ADS54T02 transmits  $2^{13}$  low resolution samples and the trigger command is locked out until completion.

The parameter N can be changed via SPI at any time. It will go in effect with the next output cycle starting with transmission of low resolution samples. The default value for N after reset is N=10.

N limit	10 (minimum)	25 (maximum)
Number of low resolution samples per cycle (2 <sup>N+3</sup> )	8,192	268,435,456
Number of high resolution samples per cycle (2 <sup>N</sup> )	1,024	33,554,432
Total amount of samples per cycle	9,216	301,989,888
Maximum number of high resolution (12-bit) samples per 1 second	83.3M	83.3M

### **Manual Trigger Mode**

The control of the high resolution output is shown below along with the two output flags (TRDY and HRES).

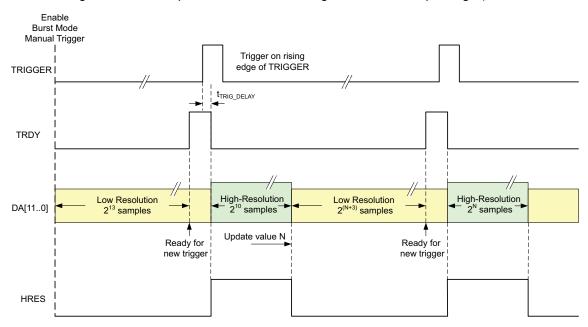


Figure 38. Triggering High Resolution Mode and Lockout Time

After enabling burst mode, the output data DA[11..0] and DB[11..0] are forced to low resolution mode for 2<sup>13</sup> samples. During that period any trigger signal is ignored. The completion of the low resolution sample cycle is signaled by a logic high on the TRDY output pins indicating that a high resolution (12-bit) data output burst can be triggered by a low to high transition on the TRIGGER input. The ADC monitors the TRIGGER input at each rising edge of the input clock.

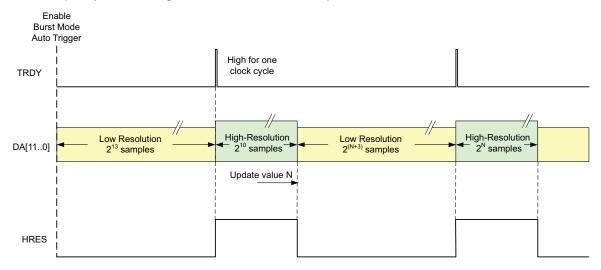
The high resolution output data starts with a delay of  $t_{TRIG\_DELAY} = 1-2$  DA/BCLK clock cycles and is indicated through the HRES data flag which stays high for all  $2^N$  high resolution samples. At completion the register value for N is verified and transmission of  $2^{(N+3)}$  low resolution data immediately follows. Once the last low resolution sample is output on the output data bus, the flag TRDY is asserted high again indicating the end of the lockout period and the next  $2^N$  high resolution samples can be triggered again.



### **Auto Trigger Mode**

This mode is enabled by setting the auto trigger bit via SPI register write and the DA/DB data outputs start in low resolution for 2<sup>13</sup> samples. Immediately following completion of transmission of the last low resolution sample, the outputs automatically start transmitting 2<sup>10</sup> high resolution samples without the need for external trigger ensuring maximum efficiency. Any input signal on the TRIGGER pins is ignored and the TRDY flag will go high only for one clock cycle with the start of the high resolution data.

The output flag HRES is aligned with the 2<sup>N</sup> high resolution output samples and the parameter N can be changed until the next output cycle starts again with low resolution output data.



### **High Resolution Output Data**

After trigger, the data outputs DA[11..0]/DB[11..0] are 12-bit resolution for  $2^N$  samples, where N is a programmable register with a range 10  $\leq$ N $\leq$ 25 (corresponding to 1024 to 33554432 samples).

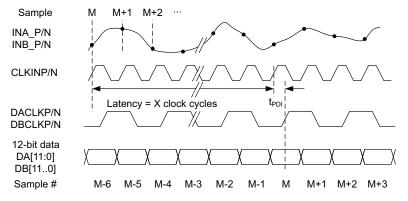


Figure 39. High Resolution Data Output Timing

After the high resolution data, the data output returns to low resolution mode, the logic level of the HRES flag returns low and the trigger is locked out for  $2^{(N+3)}$  samples. N is the sample integer resulting in a maximum output duty cycle of 1/9. During the trigger lockout time, a low to high transition on TRIGGERP/N will be ignored. After the  $2^{N+3}$  low resolution samples, the TRIGGERP/N is re-enabled for the next valid data burst.

## **Low Resolution Output Data**

There are two different options for the low resolution output data and the selection is made through SPI register control. The data can either be output at full speed (ADC sampling rate) with the output resolution limited to 7bit (7 MSBs). Alternatively the output resolution can be selected to 11bit (11 MSBs) but at a reduced effective data rate where every 4th sample gets repeated four times.



#### Full Speed - 7bit

The output data rate and timing is exactly the same as the high resolution data – only the output resolution is limited to the 7 MSBs.

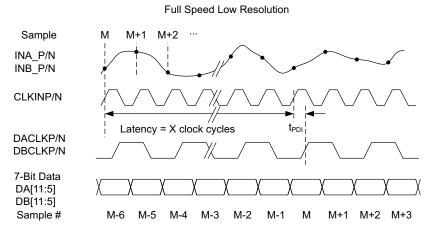


Figure 40. Full Rate Low Resolution Output Data Timing

### **Decimated Low Resolution Output Data**

In decimated low resolution mode the output data is limited to 11-bits and every sample is repeated four times so the effective data rate is 1/4 of ADC sampling rate. The latency of the ADC sample to output sample is exactly the same as for high resolution data – there is no uncertainty in which conversion sample results in the valid output data. This is because the output continues to run at the ADC sample rate – only the resolution is changed and three out of four samples are deleted.

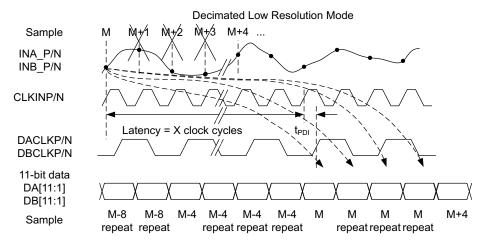
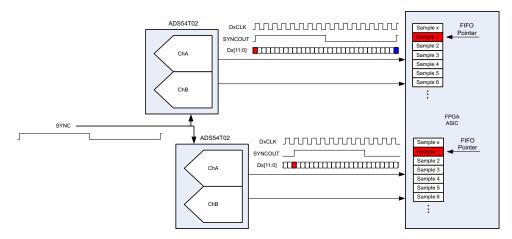


Figure 41. Decimated Low Resolution Output Data Timing Diagram



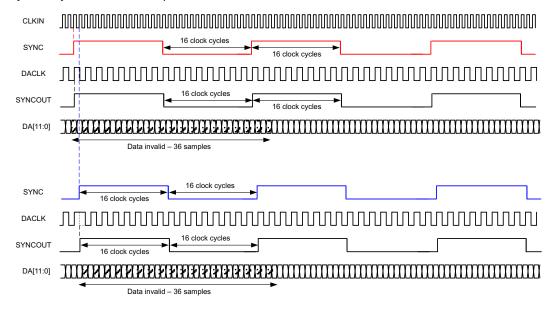
#### **MULTI DEVICE SYNCHRONIZATION**

The ADS54T02 simplifies the synchronization of data from multiple ADCs in one common receiver. Upon receiving the initial SYNC input signal, the ADS54T02 resets all the internal clocks and digital logic while also starting a SYNCOUT signal which operates on a 5bit counter (32 clock cycles). Therefore by providing a common SYNC signal to multiple ADCs their output data can be synchronized as the SYNCOUT signal marks a specific sample with the same latency in all ADCs. The SYNCOUT signal then can be used in the receiving device to synchronize the FIFO pointers across the different input data streams. Thus the output data of multiple ADCs can be aligned properly even if there are different trace lengths between the different ADCs.



The SYNC input signal should be a one time pulse to trigger the periodic 5-bit counter for SYNCOUT or a periodic signal repeating every 32 CLKIN clock cycles. It gets registered on the rising edge of the ADC input clock (CLKIN). Upon registering the initial rising edge of the SYNC signal, the internal clocks and logic get reset which results in invalid output data for 36 samples (1 complete sync cycle and 4 additional samples). The SYNCOUT signal starts with the next output clock (DACLK) rising edge and operates on a 5-bit counter. If a SYNCIN rising edge gets registered at a new position, the counter gets reset and SYNCOUT starts from the new position.

Since the ADS54T02 output interface operates with a DDR clock, the synchronization can happen on the rising edge or falling edge sample. Synchronization on the falling edge sample will result in a half cycle clock stretch of DA/BCLK. For convenience the SYNCOUT signal is available on the ChA/B output LVDS bus. When using decimation the SYNCOUT signal still operates on 32 clock cycles of CLKIN but since the output data is decimated by 2, only the first 18 samples should be discarded.



Submit Documentation Feedback

Copyright © 2013–2014, Texas Instruments Incorporated



#### PROGRAMMING INTERFACE

The serial interface (SIF) included in the ADS54T02 is a simple 3 or 4 pin interface. In normal mode, 3 pins are used to communicate with the device. There is an enable (SDENB), a clock (SCLK) and a bi-directional IO port (SDIO). If the user would like to use the 4 pin interface one write must be implemented in the 3 pin mode to enable 4 pin communications. In this mode, the SDO pin becomes the dedicated output. The serial interface has an 8-bit address word and a 16-bit data word. The first rising edge of SCLK after SDENB goes low will latch the read/write bit. If a high is registered then a read is requested, if it is low then a write is requested. SDENB must be brought high again before another transfer can be requested. The signal diagram is shown below:

#### **Device Initialization**

After power up, it is recommended to initialize the device through a hardware reset by applying a logic low pulse on the SRESETb pin (of width greater than 20ns), as shown in Figure 42. This resets all internal digital blocks (including SPI registers) to their default condition.

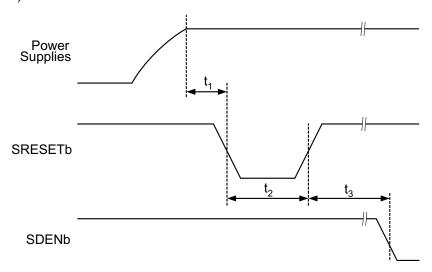


Figure 42. Device Initialization Timing Diagram

Table 1. Reset Timing

	PARAMETER	CONDITIONS	MIN	TYP	MAX	UNIT
t <sub>1</sub>	Power-on delay	Delay from power up to active low RESET pulse	3			ms
t <sub>2</sub>	Reset pulse width	Active low RESET pulse width	20			ns
$t_3$	Register write delay	Delay from RESET disable to SDENb active	100			ns

Recommended Device Initialization Sequence:

- 1. Power up
- 2. Reset ADS54T02 using hardware reset.
- 3. Apply clock and input signal.
- 4. Set register 0x01 bit D15 to "1" (ChA Corr EN) and bit D9 to "1" (ChB Corr EN) to enable gain/offset correction circuit and other desired registers.
- 5. Set register 0x03 and 0x1A bit D14 to "1" (Start Auto Corr ChA/B). This clears and resets the accumulator values in the DC and gain correction loop.
- 6. Set register 0x03 and 0x1A bit D14 to "0" (Start Auto Corr ChA/B). This starts the DC and gain auto-correction loop.

## **Serial Register Write**

The internal register of the ADS54T02 can be programmed following these steps:

- Drive SDENB pin low
- 2. Set the R/W bit to '0' (bit A7 of the 8 bit address)



- Initiate a serial interface cycle specifying the address of the register (A6 to A0) whose content has to be written
- 4. Write 16bit data which is latched on the rising edge of SCLK

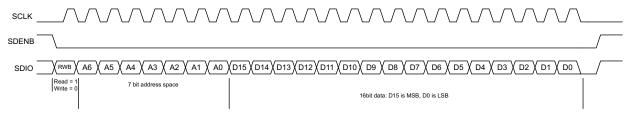


Figure 43. Serial Register Write Timing Diagram

	PARAMETER	MIN	TYP <sup>(1)</sup>	MAX	UNIT
f <sub>SCLK</sub>	SCLK frequency (equal to 1/tSCLK)	>DC		20	MHz
t <sub>SLOADS</sub>	SDENB to SCLK setup time	25			ns
t <sub>SLOADH</sub>	SCLK to SDENB hold time	25			ns
t <sub>DSU</sub>	SDIO setup time	25			ns
t <sub>DH</sub>	SDIO hold time	25			ns

(1) Typical values at +25°C; minimum and maximum values across the full temperature range: TMIN = -40°C to TMAX = +85°C, AVDD3V = 3.3V, AVDD, DRVDD = 1.9V, unless otherwise noted.



#### **Serial Register Readout**

The device includes a mode where the contents of the internal registers can be read back using the SDO/SDIO pins. This read-back mode may be useful as a diagnostic check to verify the serial interface communication between the external controller and the ADC.

- 1. Drive SDENB pin low
- 2. Set the RW bit (A7) to '1'. This setting disables any further writes to the registers
- 3. Initiate a serial interface cycle specifying the address of the register (A6 to A0) whose content has to be read.
- 4. The device outputs the contents (D15 to D0) of the selected register on the SDO/SDIO pin
- 5. The external controller can latch the contents at the SCLK rising edge.
- 6. To enable register writes, reset the RW register bit to '0'.

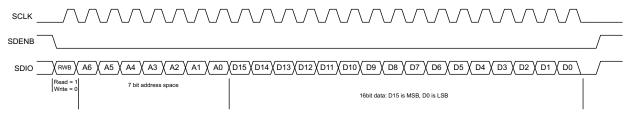


Figure 44. Serial Register Read Timing Diagram



# SERIAL REGISTER MAP(2)

(2) Multiple functions in a register can be programmed in a single write operation.

Register Address								Registe	er Data							
A7-A0 IN HEX	D15	D14	D13	D12	D11	D10	D9	D8	D7	D6	D5	D4	D3	D2	D1	D0
0	3/4 Wire SPI	DecFil/ Burst	0	ChA High/ Low Pass	0	0	ChB High/ Low Pass	0	0	0	Burst rate	0	0	Auto Trigger	0	0
1	ChA Corr EN	0	0	0	0	0	ChB Corr EN	0	0	0	0	0	Data Format	0	Hp Mode1	0
2	0	1	1	0	0	Over-range threshold 0 0 0 0 0						0	0			
3	0	Start Auto Corr ChA	0	0	1	0	1	1	0	0	0	1	1	0	0	0
Е	Sync Select										0	0				
F		Sync	Select		0	0	0	0	0	VREF Set 0 0				0	0	
1A	0	Start Auto Corr ChB	0	0	1	0	1	1	0	0	0	1	1	0	0	0
2B	0	0	0	0	0	0	0				1	Temp Senso	or			
2C					I.			Re	set							
34	0	0		Burst N	∕lode N		0	0	0	0	0	0	0	0	0	0
37			Sleep	Modes			0	0	0	0	0	0	0	0	0	0
38	HP Mode2									BIAS EN	SYNC EN	TRIGEN	1	1	1	1
ЗА							al LVDS nination	0	0	0	0	DACLK EN	DBCLK EN	0	OVRA EN	OVRB EN
66	LVDS Output Bus A EN															
67	LVDS Output Bus B EN															



## **DESCRIPTION OF SERIAL INTERFACE REGISTERS**

Register Address		Register Data														
A7-A0 in hex	D15	D14	D13	D12	D11	D10	D9	D8	D7	D6	D5	D4	D3	D2	D1	D0
0	3/4 Wire SPI	Dec Fil/ Burst	0	ChA High/ Low Pass	0	0	ChB High/ Low Pass	0	0	0	Burst rate	0	0	Auto Trigger	0	0

D15	<b>3/4 Wire SPI</b> Default 0	Enables 4-bit serial interface when set
0	3 wire SPI is used	with SDIO pin operating as bi-directional I/O port
1	4 wire SPI is used	with SDIO pin operating as data input and SDO pin as data output port.
D14	<b>DecFil/ Burst</b> Default 0	2x decimation filter (Receive Mode) is enabled when bit is set
0	Burst mode enable	e
1	2x decimation filte	r enabled
D12	ChA High/Low Pass Default 0	(Decimation filter must be enabled first: set bit D14)
0	Low Pass	
1	High Pass	
D9	ChB High/Low Pass Default 0	(Decimation filter must be enabled first: set bit D14)
D9 0	Pass	(Decimation filter must be enabled first: set bit D14)
-	Pass Default 0	(Decimation filter must be enabled first: set bit D14)
0	Pass Default 0 Low Pass	(Decimation filter must be enabled first: set bit D14)  Low resolution output data rate in burst mode
0	Pass Default 0 Low Pass High Pass Burst Rate	Low resolution output data rate in burst mode
0 1 D5	Pass Default 0 Low Pass High Pass  Burst Rate Default 0 Low resolution (98)	Low resolution output data rate in burst mode
0 1 D5	Pass Default 0 Low Pass High Pass  Burst Rate Default 0 Low resolution (98)	Low resolution output data rate in burst mode
0 1 D5 0 1	Pass Default 0 Low Pass High Pass Burst Rate Default 0 Low resolution (9th Decimated low resolution Trigger Default 0	Low resolution output data rate in burst mode  oit) full output rate solution output (4x decimation, 11bit resolution)

Copyright © 2013–2014, Texas Instruments Incorporated



Register Address		Register Data														
A7-A0 in hex	D15	D14	D13	D12	D11	D10	D9	D8	D7	D6	D5	D4	D3	D2	D1	D0
1	ChA Corr EN	0	0	0	0	0	ChB Corr EN	0	0	0	0	0	Data Format	0	HP Mode1	0

D15	ChA Corr EN (should be enabled for maximum performance) Default 0
0	Auto correction disabled
1	Auto correction enabled
D9	<b>ChB Corr EN (should be enabled for maximum performance)</b> Default 0
0	Auto correction disabled
1	Auto correction enabled
D3	<b>Data Format</b> Default 0
0	Two's complement
1	Offset Binary
D1	HP Mode 1

1 Must be set to 1 for optimum performance

Default 0



www.ti.com

Register Address								Regist	er Data							
A7-A0 in hex	D15	D14	D13	D12	D11	D10	D9	D8	D7	D6	D5	D4	D3	D2	D1	D0
2	0	1	1	0	0	Ov	er-range	e thresh	old	0	0	0	0	0	0	0

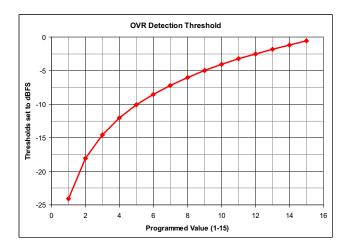
D14 Read back 1.

D13 Read back 1.

D10-D7 Over-range threshold

The over-range detection is triggered 12 output clock cycles after the overload condition occurs. The threshold at which the OVR is triggered = 1.0V x [decimal value of <Over-range threshold>]/16. After power up or reset, the default value is 15 (decimal) which corresponds to a OVR threshold of 0.56dB below fullscale (20\*log(15/16)). This OVR threshold is applicable to both channels.

Default 1111



Register Address	Register Data															
A7-A0 in hex	D15	D14	D13	D12	D11	D10	D9	D8	D7	D6	D5	D4	D3	D2	D1	D0
3	0	Start Auto Corr ChA	0	0	1	0	1	1	0	0	0	1	1	0	0	0

D14 Start Auto Corr ChA Starts DC offset and Gain correction loop for ChA

Default 1

0 Starts the DC offset and Gain correction loops

Clears DC offset correction value to 0 and Gain correction value to 1

D11, 9, 8, 4, 3 Must be set to 1 for maximum performance

Default 1



Register Address								Regist	er Data							
A7-A0 in hex	D15	D14	D13	D12	D11	D10	D9	D8	D7	D6	D5	D4	D3	D2	D1	D0
E							Sync	Select							0	0

D15-D2 Sync Select Sync selection for the clock generator block (also

Default 1010 1010 need to see address 0x0F)

1010 10

0000 0000 0000 00 Sync is disabled

0101 0101 0101 01 Sync is set to one shot (one time synchronization only)

1010 1010 1010 10 Sync is derived from SYNC input pins

1111 1111 111 not supported

Register Address								Regist	er Data							
A7-A0 in hex	D15	D14	D13	D12	D11	D10	D9	D8	D7	D6	D5	D4	D3	D2	D1	D0
F	Sync Select			0	0	0	0	0	\	REF Se	el	0	0	0	0	

D15-D12 Sync Select Sync selection for the clock generator block

Default 1010

0000 Sync is disabled

O101 Sync is set to one shot (one time synchronization only)

1010 Sync is derived from SYNC input pins

1111 not supported

D6-D4 VREF SEL Internal voltage reference selection

Default 000

000 1.0V 001 1.25V 010 0.9V 011 0.8V 100 1.15V

Others external reference

Register Address	Register Data															
A7-A0 in hex	D15	D14	D13	D12	D11	D10	D9	D8	D7	D6	D5	D4	D3	D2	D1	D0
1A	0	Start Auto Corr ChB	0	0	1	0	1	1	0	0	0	1	1	0	0	0

D14 Start Auto Corr ChB Starts DC offset and Gain correction loop for ChB

Default 1

0 Starts the DC offset and Gain correction loops

Clears DC offset correction value to 0 and Gain correction value to 1

D11, 9, 8, 4, 3 Must be set to 1 for maximum performance

Default 1



#### www.ti.com

Register Address								Regist	er Data							
A7-A0 in hex	D15	D14	D13	D12	D11	D10	D9	D8	D7	D6	D5	D4	D3	D2	D1	D0
2B	0	0	0	0	0	0	0	Temp Sensor								

D8-D0 **Temp Sensor** Internal temperature sensor value – read only

Register Address								Regist	er Data							
A7-A0 in hex	D15	D14	D13	D12	D11	D10	D9	D8	D7	D6	D5	D4	D3	D2	D1	D0
2C		Reset														

D15-D0 Reset

Default 0000 This is a software reset to reset all SPI registers to their default value. Self

clears to 0.

1101001011110000 Perform software reset

Register Address								Regist	er Data							
A7-A0 in hex	D15	D14	D13	D12	D11	D10	D9	D8	D7	D6	D5	D4	D3	D2	D1	D0
34	0	0		Burst Mode N			0	0	0	0	0	0	0	0	0	0

D13-D10 Burst Mode N This is the parameter that sets the amount of high resolution

Default 0000 samples in burst mode

0000 N = 10 0001 N = 11

1111 N = 25

Register Address								Regist	er Data							
A7-A0 in hex	D15	D14	D13	D12	D11	D10	D9	D8	D7	D6	D5	D4	D3	D2	D1	D0
37		Sleep Modes						0	0	0	0	0	0	0	0	0

D15-D14 Sleep Modes Sleep mode selection which is controlled by the ENABLE pin. Sleep modes are active when

Default 00 ENABLE pin goes low.

000000 Complete shut down Wake up time 2.5 ms
100000 Stand-by mode Wake up time 100 μs
110000 Deep sleep mode Wake up time 20 μs
110101 Light sleep mode Wake up time 2 μs



Register Address								Regist	er Data							
A7-A0 in hex	D15	15 D14 D13 D12 D11 D10 D9 D8 D7										D4	D3	D2	D1	D0
38		HP Mode 2										TRIG EN	1	1	1	1

D15-D7 **HP Mode 2** 

Default 111111111

1 Set to 1 for normal operation

D6 BIAS EN Enables internal fuse bias voltages – can be disabled after

Default 1 power up to save power.

0 Internal bias powered

down

1 Internal bias enabled

D5 **SYNC EN** Enables the SYNC input buffer.

Default 1

0 SYNC input buffer

disabled

1 SYNC input bffer enabled

D4 TRIG EN Enables the TRIGGER input buffer.

Default 1

0 TRIGGER input buffer

disabled

1 TRIGGER input bffer

enabled

D3-D0 Read back 1

Submit Documentation Feedback

Copyright © 2013–2014, Texas Instruments Incorporated



## www.ti.com

Register Address								Re	Register Data													
A7-A0 in hex	D15	D14	D13	D12	D11	D10	D9	D8	D7	D6	D5	D4	D3	D2	D1	D0						
3A	LVDS Current Strength			LVDS	S SW		rnal DS nation	0	0	0	0	DACLK EN	DBCLK EN	0	OVRA EN	OVRB EN						

D15-D13	LVDS Current Strength Default 000	İ	LVDS output current strength.
000	2 mA	100	3 mA
001	2.25 mA	101	3.25 mA
010	2.5 mA	110	3.5 mA
011	2.75 mA	111	3.75 mA
D12-D11	LVDS SW Default 01	LVDS	driver internal switch setting – correct range must be set for setting in D15-D13
01	2 mA to 2.75 r	nA	
11	3mA to 3.75m	A	
D10-D9	Internal LVDS Termination Default 00	•	Internal termination
00	2 kΩ		
01	200 Ω		
10	200 Ω		
11	100 Ω		
D4	DACLK EN Default 1		Enable DACLK output buffer
0	DACLK output	buffer	powered down
1	DACLK output	buffer	enabled
D3	DBCLK EN Default 1		Enable DBCLK output buffer
0	DBCLK output	buffer	powered down
1	DBCLK output	buffer	enabled
D1	OVRA EN Default 1	Enabl	e OVRA output buffer
0	OVRA output I	ouffer p	owered down
1	OVRA output l	ouffer e	nabled
D0	OVRB EN Default 1	Enabl	e OVRB output buffer
0	OVRB output I	ouffer p	owered down
1	OVRB output I	ouffer e	nabled



Register Address								Regist	er Data							
A7-A0 in hex	D15	D14	D13	D12	D11	D10	D9	D8	D7	D6	D5	D4	D3	D2	D1	D0
66		LVDS Output Bus A EN														

D15-D0	LVDS Output Bus A EN Individual L\ Default FFFF	DS output pin power down for channel A
0	Output is powered down	
1	Output is enabled	
D15	corresponds to TRDYP/N (pins N7, P7)	
D14	corresponds to HRESP/N (pins N6, P6)	
D13	SYNCOUTP/N (pins N5, P5)	
D12	Pins N4, P4 (no connect pins) which are no power savings	t used and should be powered down for
D11-D0	corresponds to DA11-DA0	

Register Address								Regist	er Data							
A7-A0 in hex	D15	D14	D13	D12	D11	D10	D9	D8	D7	D6	D5	D4	D3	D2	D1	D0
67	LVDS Output Bus B EN															

D15-D0	LVDS Output Bus B EN Default FFFF	ndividual LVDS output pin power down for channel B
0	Output is powered down	
1	Output is enabled	
D15	corresponds to TRDYP/N (pins	G3, G4)
D14	corresponds to HRESP/N (pins	F3, F4)
D13	SYNCOUTP/N (pins F1, F2)	
D12	Pins E3, E4 (no connect pins) w power savings	which are not used and should be powered down for
D11-D0	corresponds to DB11-DB0	

0 Submit Documentation Feedback



## **REVISION HISTORY**

Cł	nanges from Revision A (August 2013) to Revision B	Page
•	Added text to TRDYP/N description	4
•	Added text to HRESP/N description	4
•	Added text and figure to TEST PATTERN OUTPUT section	20
•	Deleted text from last paragraph in INTERLEAVING CORRECTION section	23
•	Changed 9 or 11bit to 7 or 11bit in FEEDBACK MODE: BURST MODE section	25
•	Changed Figure 40	27
•	Changed second paragraph in MULTI DEVICE SYNCHRONIZATION section	28
•	Deleted Register Initialization section and added Device Initialization section	29
•	Changed Register Address 2 Bit D13 from 0 to 1 in SERIAL REGISTER MAP	32
•	Changed Register Address E Bits D1 and D0 to 0 in SERIAL REGISTER MAP	32
•	Changed Register Address 38 Bits D3 to D0 from 0 to 1 in SERIAL REGISTER MAP	
•	Changed Register Address 1 Bit D14 from 1 to 0	
•	Changed Register Address 2 Bit D13 from 0 to 1 and add D13 Read back 1	
•	Changed Register Address E Bit D1 and D0 to 0	36
•	Changed Register Address 38 Bits D3 to D0 from 0 to 1 and add D3 to D0 Read back 1	38
•	Changed Register Address 66 D15-D10 to D15-D0 and DA11-D0 to DA11-DA0	40
•	Changed Register Address 67 D15-D10 to D15-D0	40
Cł	nanges from Original (January 2013) to Revision A	Page
•	Deleted	4
•	Changed package from QFN to nFBGA in THERMAL INFORMATION	5
•	Changed D15-10 in register 66 From: Individual LVDS output pin power down for channel B To: Individual LVDS output pin power down for channel A	
•	Changed D15 in register 66 From: corresponds to TRDYP/N (pins G3, G4) To: corresponds to TRDYP/N (pins N7, P7)	40
•	Changed D14 in register 66 From: corresponds to HRESP/N (pins F3, F4) To: corresponds to HRESP/N (pins N6, P6)	40
•	Changed D13 in Register 66 From: SYNCOUTP/N (pins F1, F2) To: SYNCOUTP/N (pins N5, P5)	
•	Changed D12 in Register 66 From: "Pins E3, E4" To: "Pins N4, P4"	
•	Changed D11-D10 - corresponds to DB11-DB0 in Register 66 To: D11-D0 - corresponds to DA11-D0	
•	Changed D11-D10 - corresponds to DB11-DB0 in Register 67 To: D11-D0 - corresponds to DB11-DB0	

www.ti.com 10-Nov-2025

#### PACKAGING INFORMATION

Orderable part number	Status	Material type	Package   Pins	Package qty   Carrier	Carrier RoHS Lea (3) Bal		MSL rating/ Peak reflow	Op temp (°C)	Part marking (6)
ADS54T02IZAY	Active	Production	NFBGA (ZAY)   196	160   JEDEC TRAY (5+1)	Yes	SNAGCU	Level-3-260C-168 HR	-40 to 85	ADS54T02I
ADS54T02IZAY.B	Active	Production	NFBGA (ZAY)   196	160   JEDEC TRAY (5+1)	Yes	SNAGCU	Level-3-260C-168 HR	-40 to 85	ADS54T02I
ADS54T02IZAYR	Active	Production	NFBGA (ZAY)   196	1000   LARGE T&R	Yes	SNAGCU	Level-3-260C-168 HR	-40 to 85	ADS54T02I
ADS54T02IZAYR.B	Active	Production	NFBGA (ZAY)   196	1000   LARGE T&R	Yes	SNAGCU	Level-3-260C-168 HR	-40 to 85	ADS54T02I

<sup>(1)</sup> Status: For more details on status, see our product life cycle.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

Important Information and Disclaimer: The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

<sup>(2)</sup> Material type: When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

<sup>(3)</sup> RoHS values: Yes, No, RoHS Exempt. See the TI RoHS Statement for additional information and value definition.

<sup>(4)</sup> Lead finish/Ball material: Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

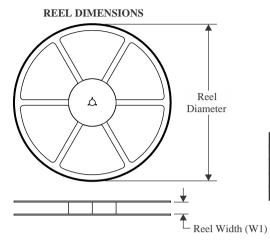
<sup>(5)</sup> MSL rating/Peak reflow: The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

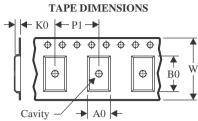
<sup>(6)</sup> Part marking: There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

## **PACKAGE MATERIALS INFORMATION**

www.ti.com 23-May-2025

## TAPE AND REEL INFORMATION





A0	Dimension designed to accommodate the component width
В0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

## QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE

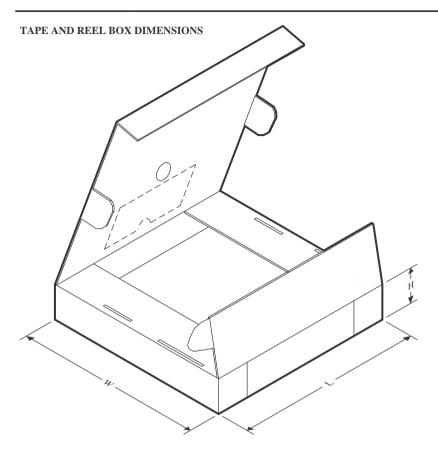


#### \*All dimensions are nominal

Device	U	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
ADS54T02IZAYR	NFBGA	ZAY	196	1000	330.0	24.4	12.3	12.3	2.3	16.0	24.0	Q1

# **PACKAGE MATERIALS INFORMATION**

www.ti.com 23-May-2025



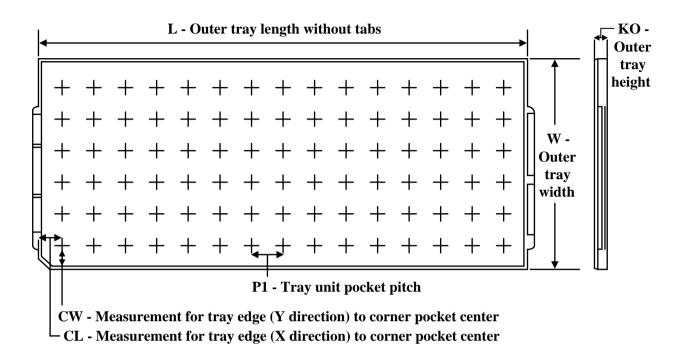
## \*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)	
ADS54T02IZAYR	NFBGA	ZAY	196	1000	350.0	350.0	43.0	



www.ti.com 23-May-2025

## **TRAY**



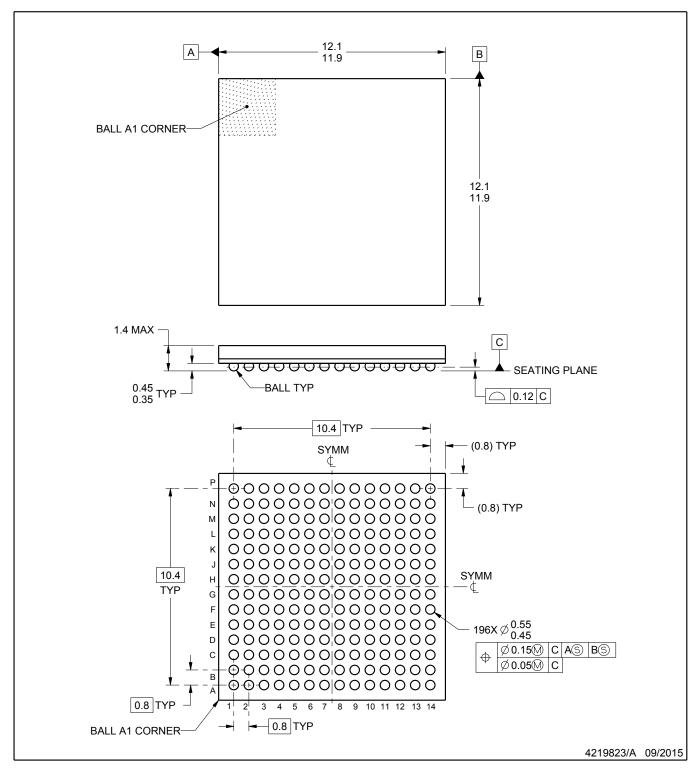
Chamfer on Tray corner indicates Pin 1 orientation of packed units.

#### \*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	Unit array matrix	Max temperature (°C)	L (mm)	W (mm)	Κ0 (μm)	P1 (mm)	CL (mm)	CW (mm)
ADS54T02IZAY	ZAY	NFBGA	196	160	8 x 20	150	315	135.9	7620	15.4	11.2	19.65
ADS54T02IZAY.B	ZAY	NFBGA	196	160	8 x 20	150	315	135.9	7620	15.4	11.2	19.65



PLASTIC BALL GRID ARRAY

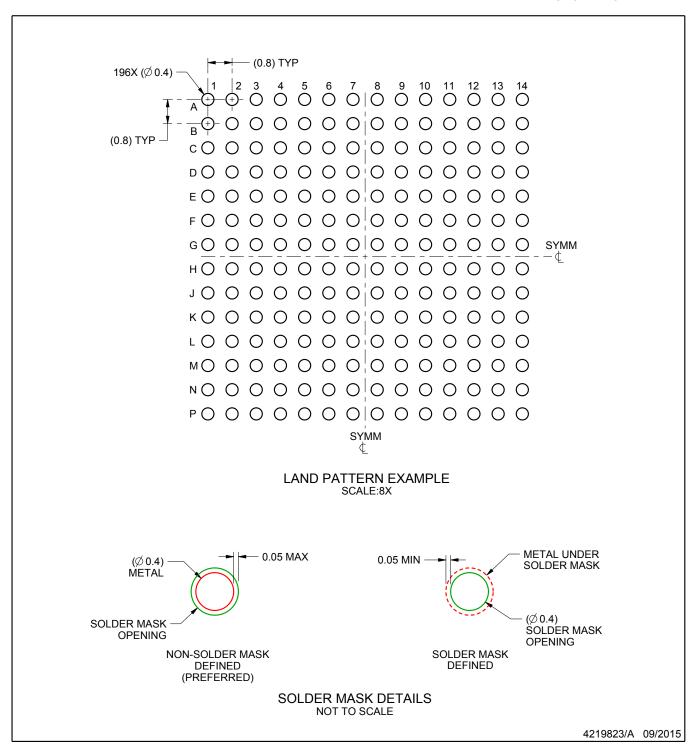


#### NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
- 2. This drawing is subject to change without notice.



PLASTIC BALL GRID ARRAY

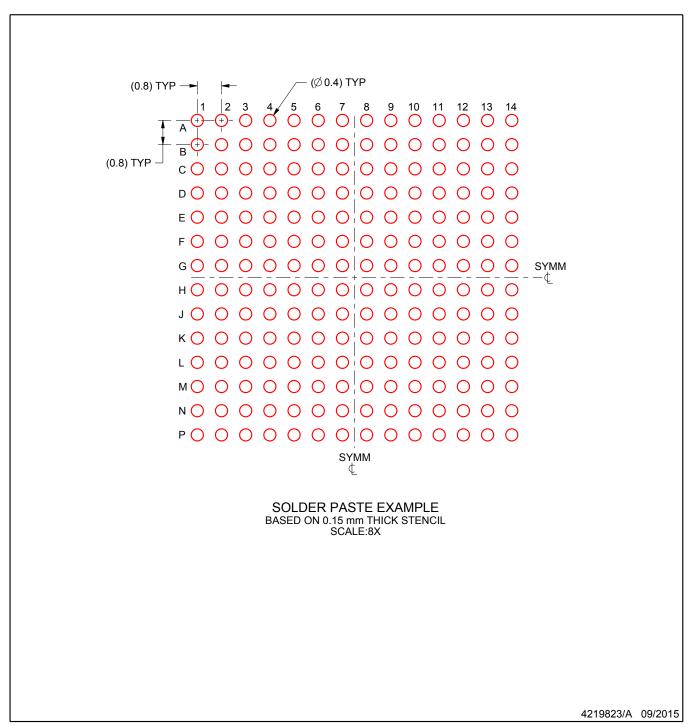


NOTES: (continued)

3. Final dimensions may vary due to manufacturing tolerance considerations and also routing constraints. For information, see Texas Instruments literature number SPRAA99 (www.ti.com/lit/spraa99).



PLASTIC BALL GRID ARRAY



NOTES: (continued)

4. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release.



## IMPORTANT NOTICE AND DISCLAIMER

TI PROVIDES TECHNICAL AND RELIABILITY DATA (INCLUDING DATASHEETS), DESIGN RESOURCES (INCLUDING REFERENCE DESIGNS), APPLICATION OR OTHER DESIGN ADVICE, WEB TOOLS, SAFETY INFORMATION, AND OTHER RESOURCES "AS IS" AND WITH ALL FAULTS, AND DISCLAIMS ALL WARRANTIES, EXPRESS AND IMPLIED, INCLUDING WITHOUT LIMITATION ANY IMPLIED WARRANTIES OF MERCHANTABILITY, FITNESS FOR A PARTICULAR PURPOSE OR NON-INFRINGEMENT OF THIRD PARTY INTELLECTUAL PROPERTY RIGHTS.

These resources are intended for skilled developers designing with TI products. You are solely responsible for (1) selecting the appropriate TI products for your application, (2) designing, validating and testing your application, and (3) ensuring your application meets applicable standards, and any other safety, security, regulatory or other requirements.

These resources are subject to change without notice. TI grants you permission to use these resources only for development of an application that uses the TI products described in the resource. Other reproduction and display of these resources is prohibited. No license is granted to any other TI intellectual property right or to any third party intellectual property right. TI disclaims responsibility for, and you fully indemnify TI and its representatives against any claims, damages, costs, losses, and liabilities arising out of your use of these resources.

TI's products are provided subject to TI's Terms of Sale, TI's General Quality Guidelines, or other applicable terms available either on ti.com or provided in conjunction with such TI products. TI's provision of these resources does not expand or otherwise alter TI's applicable warranties or warranty disclaimers for TI products. Unless TI explicitly designates a product as custom or customer-specified, TI products are standard, catalog, general purpose devices.

TI objects to and rejects any additional or different terms you may propose.

Copyright © 2025, Texas Instruments Incorporated

Last updated 10/2025